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Docket No.: M4065.0513/P513-A
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Hasan Nejad et al.

Application No.: 10/761,247

Confirmation No.: 2010

Filed: January 22, 2004

Art Unit: 2822

OK
to
enter

For: MRAM MEMORY CELL HAVING AN
ELECTROPLATED BOTTOM LAYER
(amended)

Examiner: A. Zarabian

AMENDMENT IN RESPONSE TO FINAL OFFICE ACTION

MP
3/06
MS Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

INTRODUCTORY COMMENTS

In response to the Final Office Action dated November 21, 2005, please amend the above-identified U.S. patent application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 5 of this paper.